

N-channel TrenchMOS standard level FET 11 September 2012

Product data sheet

Product profile 1.

1.1 General description

Standard level N-channel MOSFET in a SOT78 package using TrenchMOS technology. This product has been designed and qualified to AEC Q101 standard for use in high performance automotive applications.

1.2 Features and benefits

- AEC Q101 compliant •
- Repetitive avalanche rated
- Suitable for thermally demanding environments due to 175 °C rating
- True standard level gate with VGS(th) rating of greater than 1V at 175 °C •

1.3 Applications

- 12 V Automotive systems
- Motors, lamps and solenoid control •
- Start-Stop micro-hybrid applications •
- Transmission control
- Ultra high performance power switching •

1.4 Quick reference data

0	Description				-		11.11
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	-	40	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 1</u>	[1]	-	-	100	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	234	W
Static chara	cteristics	·					
R _{DSon}	drain-source on-state	V _{GS} = 10 V; I _D = 25 A; T _i = 25 °C;		-	2.6	3.1	mΩ
	resistance	Fig. 11					
Dynamic characteristics							
Q _{GD}	gate-drain charge	V_{GS} = 10 V; I _D = 25 A; V _{DS} = 32 V;		-	22	-	nC
		Fig. 13; Fig. 14					

[1] Continuous current is limited by package.

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2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	D
2	D	drain		
3	S	source		G - UF A
mb	D	mounting base; connected to drain	TO-220AB (SOT78A)	mbb076 S

3. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
BUK753R1-40E	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78A				

4. Marking

Table 4. Marking codes	
Type number	Marking code
BUK753R1-40E	BUK753R1-40E

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	40	V
V _{DGR}	drain-gate voltage	R _{GS} = 20 kΩ		-	40	V
V _{GS}	gate-source voltage	T _j ≤ 175 °C; DC		-20	20	V
I _D	drain current	T _{mb} = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u>	[1]	-	100	А
		T _{mb} = 100 °C; V _{GS} = 10 V; <u>Fig. 1</u>	[1]	-	100	А
I _{DM}	peak drain current	T_{mb} = 25 °C; pulsed; $t_p \le 10 \ \mu$ s; Fig. 4	<u>.</u>	-	798	А

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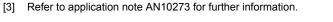
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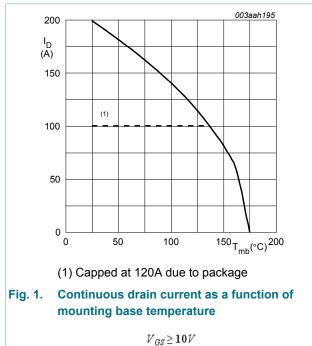
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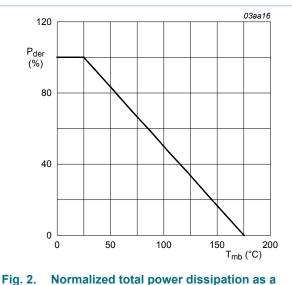
Symbol	Parameter	Conditions		Min	Max	Unit	
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	234	W	
T _{stg}	storage temperature			-55	175	°C	
Tj	junction temperature			-55	175	°C	
Source-drain	n diode		1				
I _S	source current	T _{mb} = 25 °C	[1]	-	100	А	
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^\circ C$		-	798	А	
Avalanche ruggedness							
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$\begin{split} I_D &= 100 \text{ A}; V_{sup} \leq 40 \text{V}; \text{R}_{GS} = 50 \Omega; \\ V_{GS} &= 10 \text{V}; \text{T}_{j(init)} = 25 ^{\circ}\text{C}; \text{unclamped}; \\ \hline \text{Fig. 3} \end{split}$	[<u>2][3]</u>	-	419	mJ	

Continuous current is limited by package. [1]

Single-pulse avalanche rating limited by maximum junction temperature of 175 °C. Refer to application note AN10273 for further information. [2]







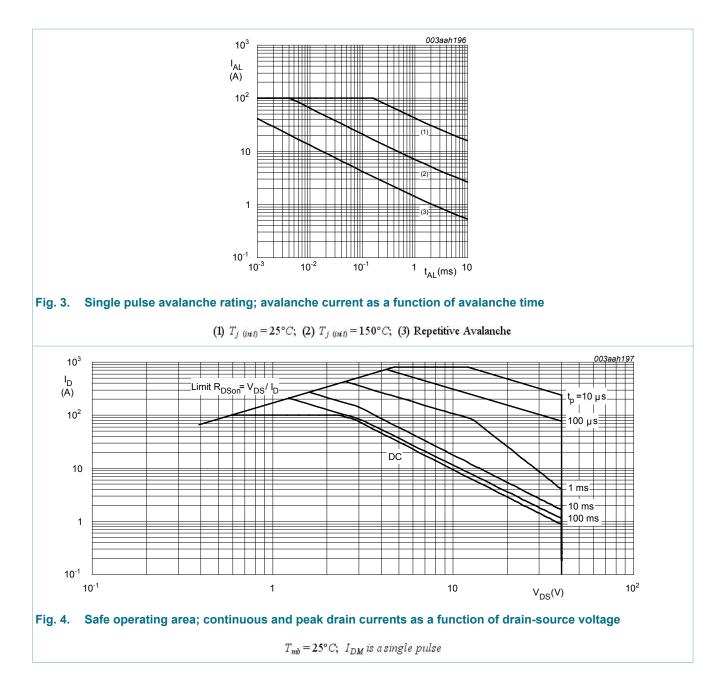
function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

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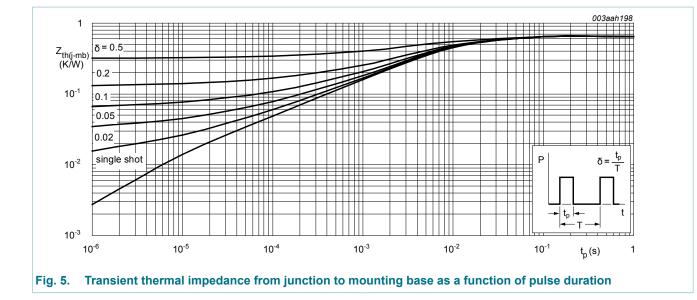
Thermal characteristics 6.

Table 6. T	hermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	-	0.64	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	vertical in still air	-	60	-	K/W
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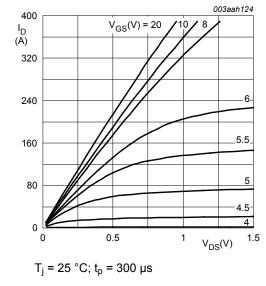


7. Characteristics

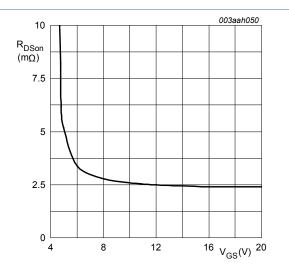
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static chara	acteristics	· · ·	I			
V _{(BR)DSS}	drain-source	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	40	-	-	V
breakdown voltage		I_D = 250 µA; V_{GS} = 0 V; T_j = -55 °C	36	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C};$ Fig. 9; Fig. 10	2.4	3	4	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ Fig. 10	-	-	4.5	V
		I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 175 °C; Fig. 10	1	-	-	V
I _{DSS}	drain leakage current	V_{DS} = 40 V; V_{GS} = 0 V; T_j = 25 °C	-	0.2	2	μA
		V_{DS} = 40 V; V_{GS} = 0 V; T_j = 175 °C	-	-	500	μA
I _{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 11	-	2.6	3.1	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 12; Fig. 11	-	-	5.9	mΩ
Dynamic cl	naracteristics	· · · ·				
Q _{G(tot)}	total gate charge	$I_D = 25 \text{ A}; V_{DS} = 32 \text{ V}; V_{GS} = 10 \text{ V};$	-	79	-	nC
Q _{GS}	gate-source charge	Fig. 13; Fig. 14	-	20	-	nC
Q _{GD}	gate-drain charge		-	22	-	nC

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{iss}	input capacitance	V_{GS} = 0 V; V_{DS} = 25 V; f = 1 MHz;	-	4650	6200	pF
C _{oss}	output capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 25 \text{ V}; \text{ f} = 1 \text{ MHz};$ $T_j = 25 \text{ °C}; \underline{\text{Fig. 15}}$ $V_{DS} = 30 \text{ V}; \text{ R}_L = 1.2 \Omega; \text{ V}_{GS} = 10 \text{ V};$ $R_{G(ext)} = 5 \Omega$ from upper edge of drain mounting base to center of die from source lead to source bonding pad	 -	885	1065	pF
C _{rss}	reverse transfer capacitance		-	470	640	pF
t _{d(on)}	turn-on delay time	V_{DS} = 30 V; R _L = 1.2 Ω; V _{GS} = 10 V;	-	24	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$	-	29	-	ns
t _{d(off)}	turn-off delay time		-	54	-	ns
t _f	fall time		-	32	-	ns
L _D	internal drain inductance		-	2.5	-	nH
L _S	internal source inductance		-	7.5	-	nH
Source-dra	in diode	I				
V _{SD}	source-drain voltage	I_{S} = 25 A; V_{GS} = 0 V; T_{j} = 25 °C; <u>Fig. 16</u>	-	0.82	1.2	V
t _{rr}	reverse recovery time	I_{S} = 20 A; d I_{S} /dt = -100 A/µs; V _{GS} = 0 V;	-	38.8	-	ns
Q _r	recovered charge	V _{DS} = 25 V	-	44.6	-	nC





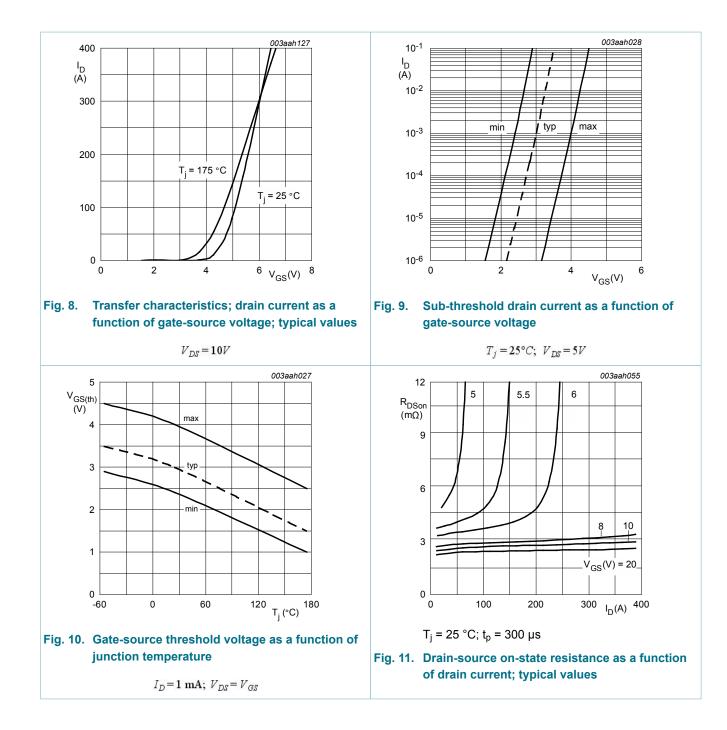




 $T_j = 25^{\circ}C; \ I_D = 25A$

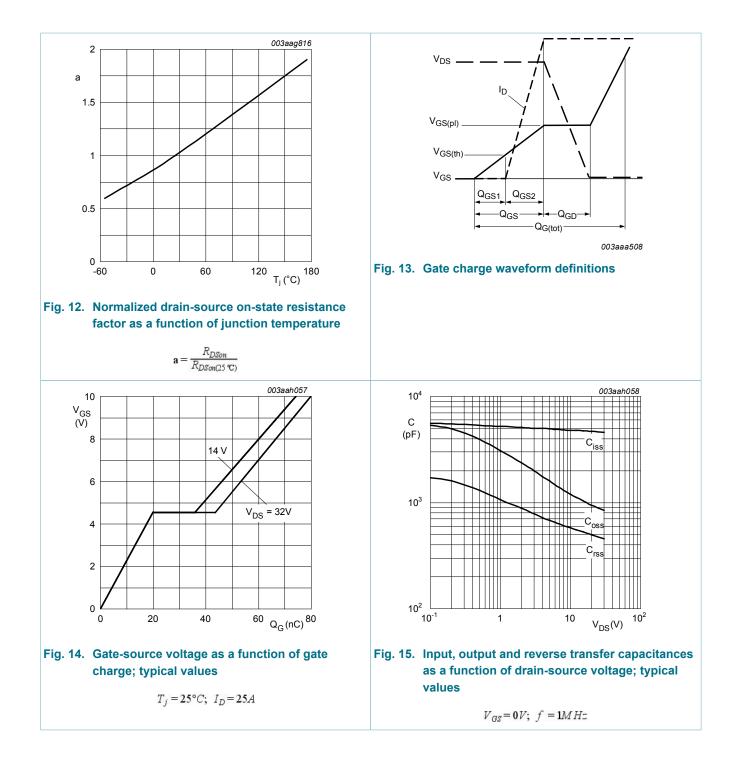
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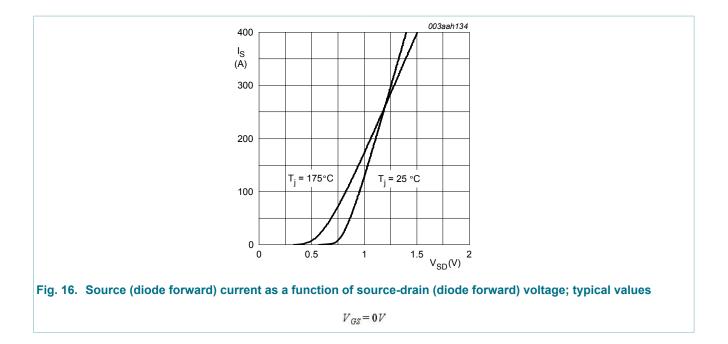
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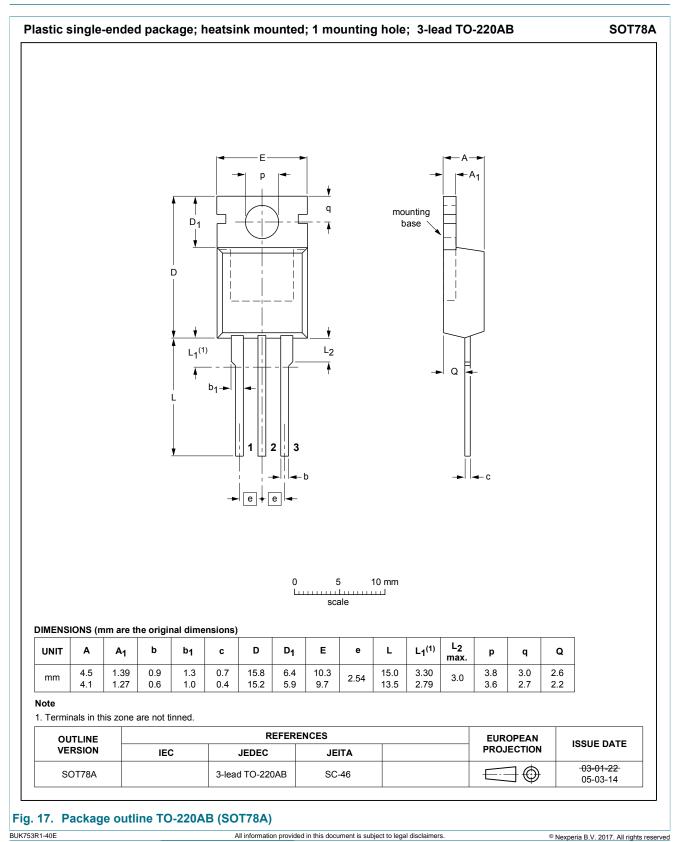
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8. Package outline



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9. Legal information

9.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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